

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 / (978) 620-2600 / Fax: (978) 689-0803 Website: http: //www.microsemi.com

PNP SMALL SIGNAL SILICON TRANSISTOR

Qualified per MIL-PRF-19500/291

| DEVICES | | LEVELS |
|------------|----------------|--------|
| 2N2906A | 2N2907A | JAN |
| 2N2906AL | 2N2907AL | JANTX |
| 2N2906AUA | 2N2907AUA | JANTXV |
| 2N2906AUB | 2N2907AUB | JANS |
| 2N2906AUBC | * 2N2907AUBC * | |

* Available to JANS quality level only.

ABSOLUTE MAXIMUM RATINGS ($T_c = +25 \circ C$ unless otherwise noted)

| Parameters / Test Conditions | Symbol | Value | Unit |
|--|------------------------------------|-------------|------|
| Collector-Emitter Voltage | V _{CEO} | 60 | Vdc |
| Collector-Base Voltage | V _{CBO} | 60 | Vdc |
| Emitter-Base Voltage | V _{EBO} | 5.0 | Vdc |
| Collector Current | I _C | 600 | mAdc |
| Total Power Dissipation @ $T_A = +25^{\circ}C$ | P _T | 0.5 | W |
| Operating & Storage Junction Temperature Range | T _{op} , T _{stg} | -65 to +200 | °C |



TO-18 (TO-206AA) 2N2906A, 2N2907A

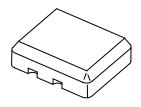
Note: Consult 19500/291 for Thermal Performance Curves.

ELECTRICAL CHARACTERISTICS ($T_A = +25^{\circ}C$, unless otherwise noted)

| Parameters / Test Conditions | Symbol | Min. | Max. | Unit | | | |
|---|----------------------|------|----------|--------------|--|--|--|
| OFF CHARACTERTICS | | | | | | | |
| Collector-Emitter Breakdown Voltage $I_C = 10$ mAdc | V _{(BR)CEO} | 60 | | Vdc | | | |
| Collector-Base Cutoff Current $V_{CB} = 60Vdc$ $V_{CB} = 50Vdc$ | I _{CBO} | | 10 10 | μAdc ηAdc | | | |
| | I _{EBO} | | 50 10 | ηAdc μAdc | | | |
| Collector-Emitter Cutoff Current $V_{CE} = 50$ Vdc | I _{CES} | | 50 | ηAdc | | | |



4 PIN 2N2906AUA, 2N2907AUA



3 PIN 2N2906AUB, 2N2907AUB 2N2906AUBC, 2N2907AUBC (UBC = Ceramic Lid Version)



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ELECTRICAL CHARACTERISTICS ($T_A = +25^{\circ}C$, unless otherwise noted)

| Parameters / Test Conditions | | Symbol | Min. | Max. | Unit |
|---|--|----------------------------|-----------|------------|------|
| ON CHARACTERISTICS (4) | | | | | |
| Forward-Current Transfer Ratio | | | | | |
| $I_{C} = 0.1 \text{mAdc}, V_{CE} = 10 \text{Vdc}$ | 2N2906A, L, UA, UB, UBC 2N2907A, L, UA, UB, UBC | | 40 75 | | |
| $I_C = 1.0$ mAdc, $V_{CE} = 10$ Vdc | 2N2906A, L, UA, UB, UBC 2N2907A, L, UA, UB, UBC | | 40 100 | 175 450 | |
| $I_C = 10$ mAdc, $V_{CE} = 10$ Vdc | 2N2906A, L, UA, UB, UBC 2N2907A, L, UA, UB, UBC | \mathbf{h}_{FE} | 40 100 | | |
| $I_C = 150 \text{mAdc}, V_{CE} = 10 \text{Vdc}$ | 2N2906A, L, UA, UB, UBC 2N2907A, L, UA, UB, UBC | | 40 100 | 120 300 | |
| $I_C = 500 \text{mAdc}, V_{CE} = 10 \text{Vdc}$ | 2N2906A, L, UA, UB, UBC 2N2907A, L, UA, UB, UBC | | 40 50 | | |
| Collector-Emitter Saturation Voltage | | | | | |
| $I_{\rm C} = 150 \text{mAdc}, I_{\rm B} = 15 \text{mAdc}$ $I_{\rm C} = 500 \text{mAdc}, I_{\rm B} = 50 \text{mAdc}$ | | V _{CE(sat)} | | 0.4 1.6 | Vdc |
| Base-Emitter Saturation Voltage $I_C = 150$ mAdc, $I_B = 15$ mAdc $I_C = 500$ mAdc, $I_B = 50$ mAdc | | V _{BE(sat)} | 0.6 | 1.3 2.6 | Vdc |

DYNAMIC CHARACTERISTICS

| Parameters / Test Conditions | Symbol | Min. | Max. | Unit | |
|---|--|------------------|-----------|------|----|
| Forward Current Transfer Ratio $I_C = 1.0mAdc, V_{CE} = 10Vdc, f = 1.0kHz$ | 2N2906A, L, UA, UB, UBC 2N2907A, L, UA, UB, UBC | h _{fe} | 40 100 | | |
| Magnitude of Small–Signal Forward Current T $I_C = 20$ mAdc, $V_{CE} = 20$ Vdc, f = 100MHz | $ \mathbf{h}_{\mathrm{fe}} $ | 2.0 | | | |
| Output Capacitance $V_{CB} = 10Vdc, I_E = 0, 100kHz \le f \le 1.0MHz$ | | C _{obo} | | 8.0 | pF |
| Input Capacitance $V_{EB} = 2.0Vdc, \ I_C = 0, \ 100kHz \le f \le 1.0MHz$ | C _{ibo} | | 30 | pF | |

SWITCHING CHARACTERISTICS

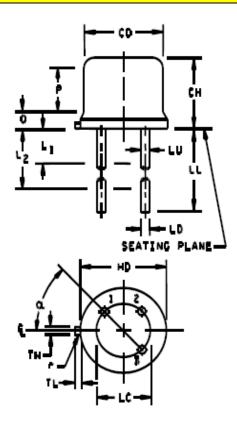
| Parameters / Test Conditions | Symbol | Min. | Max. | Unit |
|--|------------------|------|------|------|
| Turn-On Time $V_{CC} = 30Vdc; I_C = 150mAdc; I_{B1} = 50mAdc$ | t _{on} | | 45 | ηs |
| Turn-Off Time $V_{CC} = 30Vdc; I_C = 150mAdc; I_{B1} = -I_{B2} = 50mAdc$ | t _{off} | | 300 | ηs |

(4) Pulse Test: Pulse Width = 300 $\mu s,$ Duty Cycle $\leq 2.0\%.$



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PACKAGE DIMENSIONS



NOTES:

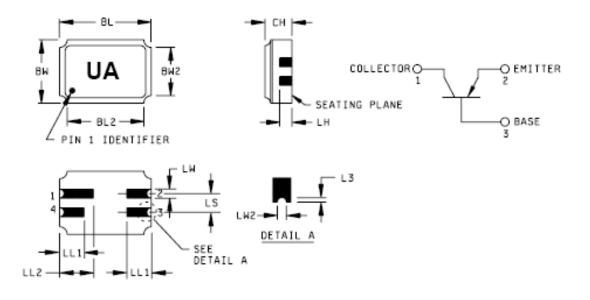
- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Beyond r (radius) maximum, TW shall be held for a minimum length of .011 inch (0.28 mm).
- 4. Dimension TL measured from maximum HD.
- 5. Body contour optional within zone defined by HD, CD, and Q.
- 6. Leads at gauge plane .054 +.001 -.000 inch (1.37 +0.03 -0.00 mm) below seating plane shall be within .007 inch (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC.
- 7. Dimension LU applies between L_1 and L_2 . Dimension LD applies between L_2 and LL minimum. Diameter is uncontrolled in L_1 and beyond LL minimum.
- 8. All three leads.
- 9. The collector shall be internally connected to the case.
- 10. Dimension r (radius) applies to both inside corners of tab.
- 11. In accordance with ASME Y14.5M, diameters are equivalent to ϕx symbology.
- 12. Lead 1 =emitter, lead 2 =base, lead 3 =collector.
- 13. For L suffix devices, dimension LL = 1.5 inches (38.10 mm) min. and 1.75 inches (44.45 mm) max.

| | | Dimensions | | | | |
|--------|------|------------|--------|------------------|--------|--|
| Symbol | Inc | hes | Millir | fillimeters Note | | |
| | Min | Max | Min | Max | | |
| CD | .178 | .195 | 4.52 | 4.95 | | |
| CH | .170 | .210 | 4.32 | 5.33 | | |
| HD | .209 | .230 | 5.31 | 5.84 | | |
| LC | .100 |) TP | 2.54 | TP | 6 | |
| LD | .016 | .021 | 0.41 | 0.53 | 7,8 | |
| LL | .500 | .750 | 12.70 | 19.05 | 7,8,13 | |
| LU | .016 | .019 | 0.41 | 0.48 | 7,8 | |
| L_1 | | .050 | | 1.27 | 7,8 | |
| L_2 | .250 | | 6.35 | | 7,8 | |
| Р | .100 | | 2.54 | | | |
| Q | | .030 | | 0.76 | 5 | |
| TL | .028 | .048 | 0.71 | 1.22 | 3,4 | |
| TW | .036 | .046 | 0.91 | 1.17 | 3 | |
| r | | .010 | | 0.25 | 10 | |
| α | 45° | TP | 45° | TP | 6 | |

FIGURE 1. Physical dimensions (similar to TO-18)



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NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Dimension "CH" controls the overall package thickness. When a window lid is used, dimension "CH" must increase by a minimum of .010 inch (0.254 mm) and a maximum of .040 inch (1.020 mm).
- 4. The corner shape (square, notch, radius) may vary at the manufacturer's option, from that shown on the drawing.
- 5. Dimensions "LW2" minimum and "L3" minimum and the appropriate castellation length define an unobstructed three-dimensional space traversing all of the ceramic layers in which a castellation was designed. (Castellations are required on the bottom two layers, optional on the top ceramic layer.) Dimension "LW2" maximum and "L3" maximum define the maximum width and depth of the castellation at any point on its surface. Measurement of these dimensions may be made prior to solder dipping.
- 6. The co-planarity deviation of all terminal contact points, as defined by the device seating plane, shall not exceed .006 inch (0.15mm) for solder dipped leadless chip carriers.
- 7. In accordance with ASME Y14.5M, diameters are equivalent to ϕx symbology.

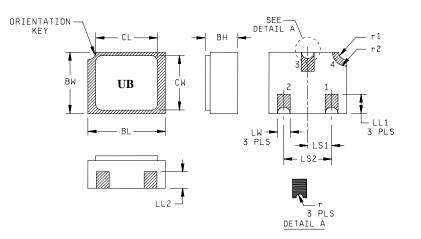
| | Dimensions | | | | |
|--------|------------|------|-------------|------|------|
| Symbol | Inches | | Millimeters | | Note |
| | Min | Max | Min | Max | |
| BL | .215 | .225 | 5.46 | 5.71 | |
| BL2 | | .225 | | 5.71 | |
| BW | .145 | .155 | 3.68 | 3.93 | |
| BW2 | | .155 | | 3.93 | |
| СН | .061 | .075 | 1.55 | 1.90 | 3 |
| L3 | .003 | .007 | 0.08 | 0.18 | 5 |
| LH | .029 | .042 | 0.74 | 1.07 | |
| LL1 | .032 | .048 | 0.81 | 1.22 | |
| LL2 | .072 | .088 | 1.83 | 2.23 | |
| LS | .045 | .055 | 1.14 | 1.39 | |
| LW | .022 | .028 | 0.56 | 0.71 | |
| LW2 | .006 | .022 | 0.15 | 0.56 | 5 |

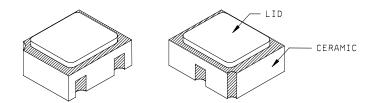
| Pin no. | 1 | 2 | 3 | 4 |
|------------|-----------|---------|------|-----|
| Transistor | Collector | Emitter | Base | N/C |

FIGURE 2. Physical dimensions, surface mount (UA version)



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| | Dimensions | | | | |
|--------|------------|------|--------|--------|------|
| Symbol | Inc | hes | Millir | neters | Note |
| | Min | Max | Min | Max | |
| BH | .046 | .056 | 1.17 | 1.42 | |
| BL | .115 | .128 | 2.92 | 3.25 | |
| BW | .085 | .108 | 2.16 | 2.74 | |
| CL | | .128 | | 3.25 | |
| CW | | .108 | | 2.74 | |
| LL1 | .022 | .038 | 0.56 | 0.96 | |
| LL2 | .017 | .035 | 0.43 | 0.89 | |

| Dimensions | | | | | |
|----------------|------|------|--------|--------|------|
| Symbol | Inc | hes | Millii | neters | Note |
| | Min | Max | Min | Max | |
| LS_1 | .036 | .040 | 0.91 | 1.02 | |
| LS_2 | .071 | .079 | 1.81 | 2.01 | |
| LW | .016 | .024 | 0.41 | 0.61 | |
| r | | .008 | | .203 | |
| \mathbf{r}_1 | | .012 | | .305 | |
| \mathbf{r}_2 | | .022 | | .559 | |
| | | | | | |

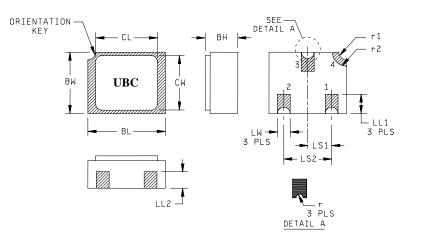
NOTES:

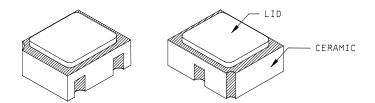
- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Pad 1 = Base, Pad 2 = Emitter, Pad 3 = Collector, Pad 4 = Shielding connected to the lid.
- 4. In accordance with ASME Y14.5M, diameters are equivalent to ϕx symbology.

FIGURE 3. Physical dimensions, surface mount (UB version)



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| Symbol | Inc | hes | Millir | neters | Note |
|--------|------|------|--------|--------|------|
| | Min | Max | Min | Max | |
| BH | .046 | .071 | 1.17 | 1.80 | |
| BL | .115 | .128 | 2.92 | 3.25 | |
| BW | .085 | .108 | 2.16 | 2.74 | |
| CL | | .128 | | 3.25 | |
| CW | | .108 | | 2.74 | |
| LL1 | .022 | .038 | 0.56 | 0.96 | |
| LL2 | .017 | .035 | 0.43 | 0.89 | |

| | Dimensions | | | | |
|-----------------------|------------|------|-------------|------|------|
| Symbol | Inches | | Millimeters | | Note |
| | Min | Max | Min | Max | |
| LS_1 | .036 | .040 | 0.91 | 1.02 | |
| LS_2 | .071 | .079 | 1.81 | 2.01 | |
| LW | .016 | .024 | 0.41 | 0.61 | |
| r | | .008 | | .203 | |
| r ₁ | | .012 | | .305 | |
| r ₂ | | .022 | | .559 | |
| | | | | | |

NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Hatched areas on package denote metalized areas.
- 4. Pad 1 = Base, Pad 2 = Emitter, Pad 3 = Collector, Pad 4 = Connected to the lid braze ring.
- 5. In accordance with ASME Y14.5M, diameters are equivalent to ϕx symbology.

FIGURE 4. Physical dimensions, surface mount (UBC version, ceramic lid)

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